Characterization of the VeloPix Detector Gain Response to Fe-55 Irradiation

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Introduction

Large Hadron Collider (LHC):

is the largest particle accelerator in the world

Various experiments, but among them LHCb

Improvement of measurements ⇒ Upgrade

Vertex Locator (VELO) detector upgraded!





Vertex Locator (VELO)

- First sub-detector particles encounter -
- Measures the ionising particles paths
- 52 Modules along travelling direction
- Surrounds *pp* interaction region





Vertex Locator (VELO)

One module = 4 sensors with 3 VeloPix ASICs each



Application-Specific Integrated Circuits (ASICs) Digital to Analog Converter (DAC)





ASIC

256x256 pixels/ASIC

 $200\,\mu m$ n-on-p Silicon depletion zone

Detection Process:

- Creation of electron-hole pairs (ehp)
- Collect current
- Digital signal [DAC]

Application-Specific Integrated Circuits (ASICs) Digital to Analog Converter (DAC)



ASIC Pixel Schematic with incident ionising particle

Signals, Noise and Thresholds

Threshold [DAC] : minimum signal amplitude required for a pixel to register a hit. [DAC] = Unit used by ASICs. Associates a Digital value to an Analog voltage or current.



Digital to Analog Converter (DAC)

Overview

Calibration and project goal:

• Conversion factor or Gain, K [e-/DAC]

Controlled scenario with radiation source \Rightarrow K [e-/DAC] for ASIC

• Compare to VeloPix ASIC design paper estimate

 $K_{est} \; [\text{e-/DAC}] = 15.45 \pm 0.51$





Overview

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 $K_{est} \; [\text{e-/DAC}] = 15.45 \pm 0.51$

Other goals:

• Explore individual vs ASIC behaviour

• Explore possible biases

Application-Specific Integrated Circuits (ASICs) Digital to Analog Converter (DAC)



Theory: Signals, Noise and Thresholds

Pixel-to-pixel variations exist \Rightarrow can be fixed with small configuration setting in pixels

⇒ Trim setting: Acts as current offset added to input signal



 10^{1}

1150 1200 1250 1300

1350 1400 1450 1500

DAC Threshold

- 2. Global threshold and noise baseline for ASIC
- 3. Masked pixel matrix



Masked: 101

1550 1600 1650 1700

Theory: Signals, Noise and Thresholds

Fe55 source:

- 60% Auger e- with energy 5.19 keV, not measured
- 28% X-rays with energy 5.9 keV
- 12% other not relevant processes

Only X-ray flux detected on ASIC

 $E_\gamma = 5.9 {
m keV}$





Theory: Signals, Noise and Thresholds

Flux vs Threshold scan



Theory: Source and Detection

Processes:

1. Photoelectric effect, $E_{
m g} = 1.12 {
m eV}$

$$E = E_{\gamma} - E_{
m g}$$
 \Rightarrow $E pprox E_{\gamma}$

2. Average electron-hole pair-creation energy in Si: $E_{ehp} = 3.69 \pm 0.11 \text{ eV/ehp}$ $\Rightarrow n_{ehp} = \frac{E_{\gamma}}{E_{ehp}} = \frac{5900 \text{ eV}}{3.69 \text{ eV/ehp}} = 1598.92 \text{ ehp}$ Energy deposition

$$ightarrow target = E_0 - E_b$$
 , n_{ehp}

$$Kigg[rac{e^-}{DAC}igg] = rac{n_{e^-}}{target} = rac{E_\gamma}{E_{ehp}}rac{1}{(E_0-E_b)}$$



 $hv > E_g$

 $E_{\gamma}=5.9 {
m keV}$,

Electron

 E_g

Flux model structure



13

Flux model structure



13

ST=2s621ms from results_ew2

1.4

1.0

0.8

-lux (hits/

it on pixel 129x128

Flux on pixel 129x12 Flux on average pixe

E0=1521.4 ±0.3. 1=0.0023±0.0006. s=2.39±0.32

Bad fit on pixel 129x128, fixed E0, f and :

Other possibilities:

$$F_{1,0}(E) = Af \cdot \frac{1}{2} \left(\frac{s}{\sqrt{\pi}} e^{-\left(\frac{E-E0}{s}\right)^2} + (E0-E) \cdot \operatorname{erfc}\left(\frac{E-E0}{s}\right) \right) + A(1-f) \cdot \frac{1}{s\sqrt{8\pi}} \cdot \operatorname{erfc}\left(\frac{E-E0}{s\sqrt{2}}\right)$$

$$F_1(E) = Af \cdot \frac{1}{2}(E0-E) \cdot \operatorname{erfc}\left(\frac{E-E0}{s}\right) + A(1-f) \cdot \frac{1}{s\sqrt{8\pi}} \cdot \operatorname{erfc}\left(\frac{E-E0}{s\sqrt{2}}\right)$$

$$F_{1,0}$$
Notation
$$F_{1,0}$$
Model name, with term0
$$F_{AB,0}(E) = A^* \cdot \left(\frac{s}{\sqrt{\pi}} e^{-\left(\frac{E-E0}{s}\right)^2} + (E0-E) \cdot \operatorname{erfc}\left(\frac{E-E0}{s}\right)\right) + B^* \cdot \frac{1}{s\sqrt{2\pi}} \cdot \operatorname{erfc}\left(\frac{E-E0}{s\sqrt{2}}\right)$$

$$F_{AB}(E) = A^* \cdot (E0-E) \operatorname{erfc}ig(rac{E-E0}{s}ig) + B^* \cdot rac{1}{s\sqrt{2\pi}} \cdot \operatorname{erfc}ig(rac{E-E0}{s\sqrt{2}}ig)$$

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Notation
$$F_{1,0}$$
Notation
$$F_{1,0}$$
Model name, with term0

Using various s parameters: 2s model

$$egin{aligned} F_{2s,0}(E) &= Af \cdot rac{1}{2} igg(rac{s_1}{\sqrt{\pi}} e^{-igg(rac{E-E0}{s_1} igg)^2} + (E0-E) \cdot ext{erfc} igg(rac{E-E0}{s_1} igg) igg) + A(1-f) \cdot rac{1}{s_2\sqrt{8\pi}} \cdot ext{erfc} igg(rac{E-E0}{s_2\sqrt{2}} igg) \ F_{2s}(E) &= rac{1}{2} fA \cdot (E0-E) \operatorname{erfc} igg(rac{E-E0}{s_1} igg) + rac{1}{2} (1-f) A \cdot rac{1}{s_2\sqrt{2\pi}} \cdot \operatorname{erfc} igg(rac{E-E0}{s_2\sqrt{2}} igg) \ F_{2s,AB}(E) &= A^* \cdot (E0-E) \cdot \operatorname{erfc} igg(rac{E-E0}{s_1} igg) + B^* \cdot rac{1}{s_2\sqrt{2\pi}} \cdot \operatorname{erfc} igg(rac{E-E0}{s_2\sqrt{2}} igg) \end{aligned}$$

Setup:

- Module at Nikhef for testing
- Cooling system used for data taking

Some data specifics:

- Two module temperatures, with same distance
- "Module production" equalisation
- MiniDAQ2 (data acquisition equipment)



Set	Label	Module Temp.	ASIC	\mathbf{ST}	nacq	Thr_{min}	Thr_{max}	Thr_{step}	Total time (h)
1	Cold	-20 ^o C	VP3-1	$2~{\rm s}621~{\rm ms}$	50	1480	1600	1	4.36
2	Warm	$20^{\circ}C$	VP3-1	$2~{\rm s621}~{\rm ms}$	100	1480	1600	1	8.73

Filtering:

Anomalies are removed.

Acquisitions that are empty or considered bad



Fitting and Pixel Categorisation:

Good: fit found and $\chi^2 < \chi^2_c$

Bad: fit found but
$$\chi^2 > \chi^2_c$$
 or unphysical parameters

Fit not found: not converging

Cut data: no enough data, faulty or masked

$$\chi^2 = \sum_i \left(\frac{O_i - F_i}{U_i}\right)^2,$$

$$\chi^2_c \, {
m with} \, lpha = 0.05 \, {
m and} \, {
m dof} = n-4$$



Average behaviour of pixels:

- Mean
- ASIC
 - Represents the average flux on the whole ASIC.
 - \circ Takes into account bad fit pixels \rightarrow not an accurate representation?
- ASICgood
 - \circ Uses only good fit pixels \rightarrow probably less biased

Throughout analysis looking at:

Distributions + Mean, ASIC & ASICgood

Can we say anything about the individual pixels from looking at the ASIC flux?

Analysis

Fit the data to the Flux equation allows us to:

$$F(E) = Af \cdot \frac{1}{2} \left(\frac{s}{\sqrt{\pi}} e^{-(\frac{E-E0}{s})^2} + (E0 - E) \cdot \operatorname{erfc}\left(\frac{E-E0}{s}\right) \right) + A(1 - f) \cdot \frac{1}{s\sqrt{8\pi}} \cdot \operatorname{erfc}\left(\frac{E-E0}{s\sqrt{2}}\right)$$
Categorise pixels
Obtain physical parameters: E0
Target and gain K[e-/DAC]
$$ASIC / \operatorname{average}$$



Individual vs Average/ASIC



Figure 9: Average and individual pixel 127 x 128 flux comparison for both the cold and warm dataset. The pink data points and line correspond to the individual pixel and the green data points and line to the average/ASIC flux.

Analysis: Flux

Individual vs Average/ASIC

ST=2s621ms from resultscalibration cold



ST=2s621ms from resultscalibration warm

Individual vs Average/ASIC

Best flux model used here: $F_{1,0}$

$$p_{thr} = rac{r_{thr}}{\Delta F_{ ext{raw},thr}} = rac{F_{ ext{raw},thr} - F_{ ext{fit}, ext{thr}}}{\Delta F_{ ext{raw},thr}}$$



Individual vs Average/ASIC

Best flux model used here: $F_{1,0}$

$$p_{thr} = rac{r_{thr}}{\Delta F_{ ext{raw}\,,thr}} = rac{F_{ ext{raw}\,,thr} - F_{ ext{fit}\,, ext{thr}}}{\Delta F_{ ext{raw}\,,thr}}$$



Individual vs Average/ASIC



Fits are still acceptable

Pixels:

ASIC:



Pixel Categorisation



Figure 13: Heatmaps showing fit type category given to the individual pixels for the *cold* and *warm* dataset.

Pixel Categorisation



Figure 13: Heatmaps showing fit type category given to the individual pixels for the *cold* and *warm* dataset.

Testing other flux models



Testing other flux models



Testing other flux models



Analysis: Parameters

Parameter distributions (good pixels only)



Analysis: Parameters

Parameter distributions (good pixels only)



Difference between individual vs ASIC \Rightarrow Is ASIC value a good choice?

Analysis: Target

We know that:

All pixels should agree on the energy deposition Shift in E_0 due to pixel variations

We can use $target = E_0 - E_b$ to:

• Correct for pixel-to-pixel variations

• Obtain energy deposition

 1.6
 Fit on pixel 12X128
 Fit

Cold

Analysis: Target

Calculation of $target = E_0 - E_b \Rightarrow$ **need** E_b

Individual pixel values

• E_b using the best prediction from equalisation

ASIC and ASICgood

•
$$E_{bASIC} = \overline{E_b}$$
, $target_{ASIC} = E_{0ASIC} - E_{bASIC}$



Analysis: Target and e-/DAC


Analysis: Gain K [e-/DAC]

Mean gain and uncertainty $SEM_{
m l}=\sigma/\sqrt{n}$



Exposure time influence

Warm dataset has twice as much exposure time

Set	Label	Module Temp.	ASIC	\mathbf{ST}	nacq	Thr_{min}	Thr_{max}	Thr_{step}	Total time (h)
1	Cold	-20° C	VP3-1	$2~{\rm s621}~{\rm ms}$	50	1480	1600	1	4.36
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New dataset variations with equal exposure time on both *warm* and *cold*:

```
calibration_nacq50: using acquisitions in the [0,50] range.
```

```
calibration_acq0to25: acqs in [0,25] range
```

```
calibration_acq25to50: acqs in [25,50] range
```

Exposure time influence



Exposure time influence



Exposure time influence



Assign a systematic uncertainty to the gain K[e-/DAC]

Exposure time influence



Assign a systematic uncertainty to the gain K[e-/DAC]

ASIC Gain makes a good prediction of Mean Gain

Pixel coordinate bias



No correlation of pixel coordinate and value of E0

35

Pixel coordinate bias

Pattern observed in equalisation

Groups: even and odd columns + 16ths rows

Based on equalisation approach:

1. Same 3 groups





Pixel coordinate bias



Pixel coordinate bias



Disagreement on mean gain among groups. Bias coming from pixel position.

K [e-/DAC] obtained for two datasets with Fe55 irradiation:



Mean Gain found is still somewhat compatible with Paper Estimate

K [e-/DAC] obtained for two datasets with Fe55 irradiation:



Maybe lower temperatures ⇒ Mean gain from data approaches Estimate Gain?

Label	Module Temp.	ASIC	Total time(h)	${\rm Gain}{\rm K}_{mean}{\rm [e-/DAC]}$
Cold	$-20^\circ\mathrm{C}$	VP3-1	4.36	$14.33 \pm 0.02 \pm 0.16$
Warm	$20^{\circ}\mathrm{C}$	VP3-1	8.73	$13.14 \pm 0.01 \pm 0.44$

Summary:

• Method to obtain Gain from irradiation of ASICs

• ASIC flux is not bad predictor for Mean Gain

• Positional bias observed



Label	Module Temp.	ASIC	Total time(h)	${\rm Gain} \: {\rm K}_{mean} \: [{\rm e}\text{-}/{\rm DAC}]$
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Future:

• Repeat analysis with new data and new equalisation running on MiniDAQ3

• Better determination of sys. uncertainty

• Repeat on other ASICs and temperatures



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Thank you for your attention.

Questions or suggestions?

Extra slides

Vertex Locator (VELO)

Table 1. Specifications of the upgraded VELO compared to those of the original version.

	2009–2018	2022
RF box inner radius (minimum thickness)	5.5 mm (300 µm)	3.5 mm (150 μm)
Inner radius of active silicon detector	8.2 mm	5.1 mm
Total fluence (silicon tip) $[n_{eq}/cm^2]$	4×10^{14}	$\sim 8 \times 10^{15}$
Sensor segmentation	$r - \phi$ strips	square pixels
Total active area of Si detectors	$0.22{ m m}^2$	$0.12 {\rm m}^2$
Pitch (strip or pixel)	37–97 μm	55 µm
Technology	n-on-n	n-on-p
Number of modules	42	52
Total number of channels	172 thousand	41 million
Readout rate [MHz]	1, analogue	40, zero suppressed
Whole-VELO data rate	150 Gbit/s	~ 2 Tbit/s
Total power dissipation (in vacuum)	800 W	$\sim 2 \mathrm{kW}$

Vertex Locator (VELO)



Vertex Locator (VELO)





Flux over thr

Flux vs Thr [DAC]





E0 Analysis

Heatmap of E0



Analysis: Target

Calculation of $target = E_0 - E_b \rightarrow \text{need } E_b$

Individual pixel values

• E_b using the best prediction from equalisation

• ΔE_b noise width of either Trim0 or TrimF

ASIC

$$target_{ASIC} = E_{0ASIC} - mean(E_b) \ \Delta targetASIC = \sqrt{(\Delta E 0_{ASIC})^2 + (\overline{\Delta E_{bASIC}})^2}$$

ASICgood (same as ASIC)



Separation: even, odd, 16th rows

Means



Separation: even, odd, 16th rows

ASIC



Separation: even, odd, 16th rows

ASICgood





Baseline inclusion approaches

_newbaseline: shift in generation of flux files.



Double s parameter in Flux equation



$$\begin{split} F(E) &= Af \cdot \frac{1}{2} \left(\underbrace{\underbrace{ \left\{ \begin{array}{c} \overbrace{ \swarrow \\ s \end{array} \right\}}^{VE0} \right\}^2}_{s} + (E0 - E) \cdot \mathrm{erfc} \left(\frac{E - E0}{s} \right) \right) \\ &+ A(1 - f) \cdot \frac{1}{s_2 \sqrt{8\pi}} \cdot \mathrm{erfc} \left(\frac{E - E0}{s_2 \sqrt{2}} \right) \end{split}$$

KASIC = n_ehp/targetASIC uKASIC = KASIC*np.sqrt((n_ehp_err/n_ehp)**2 + (utargetASIC/targetASIC)**2)

KASICgood =n_ehp/targetASICgood uKASICgood = KASICgood*np.sqrt((n_ehp_err/n_ehp)**2 + (utargetASICgood/targetASICgood)**2)



Shifting E0 by baseline before or after fit should lead to the same target result.

Calibration: shift after fitting. Get E0, then \rightarrow

 $target = E_0 - E_b$ $target_{ASIC} = E_{0ASIC} - mean(E_b)$

baselinewhilefit: shift while fitting. Get *target* directly from fit, also for ASIC

 $\Delta targetASIC = \sqrt{\Delta targetASIC}$

$$tar_{act_{ASIC}} = E_{0ASIC} - mean(E_{act_{ASIC}})$$

 $\Delta tar_{getASIC} = \sqrt{(\Delta E_{0ASIC})^2 + (\Delta E_{bASIC})^2}$

_newbaseline: shift in generation flux files



hitsASIC directly shifted with baseline_ASIC



baselinewhilefit: shift while fitting. Get target directly from fit, also for ASIC



How Gaussian is the data?


Conclusions

K [e-/DAC] obtained for two datasets of Fe55:

Comparing (cold) ASIC and ASICgood to :

Mean Gain
Comparing cold dataset to KASIC ...
Distance in standard deviations from KASIC: -0.51
Comparing cold dataset to KASICgood ...
Distance in standard deviations from KASICgood: 0.12

Estimate Gain Distance in standard deviations from KASIC: -1.97 Comparing cold to KASICgood ... Distance in standard deviations from KASICgood: -1.54